élantec
HIGH PERFORMANCE ANALOG INTEGRATED CIRCUITS

EL2008C
55 MHz 1 Amp Buffer Amplifier

Features
- High slew rate—2500 V/μs
- Wide bandwidth—
  100 MHz @ $R_L = 50\Omega$
  55 MHz @ $R_L = 10\Omega$
- Output current—1A continuous
- Output impedance—1Ω
- Quiescent current—13 mA
- Short circuit protected
- Power package with isolated metal tab

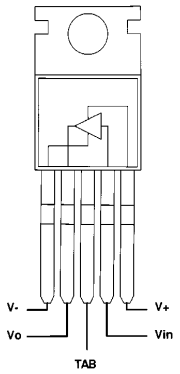
Applications
- Video distribution amplifier
- Fast op amp booster
- Flash converter driver
- Motor driver
- Pulse transformer driver
- A.T.E. pin driver

Ordering Information

Part No.	Temp. Range	Pkg.	Outline#
EL2008CT	0°C to +75°C	TO-220	MDP0028

Connection Diagram

5-Pin TO-220



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Top View

General Description

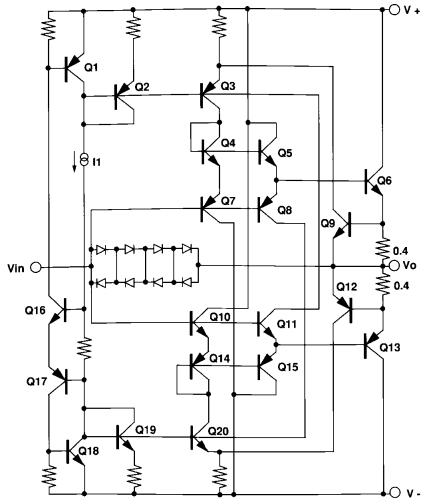
The EL2008 is a patented high speed bipolar monolithic buffer amplifier designed to provide currents over 1 amp at high frequencies, while drawing only 13 mA of quiescent supply current. The EL2008's 1500 V/μs slew rate and 55 MHz bandwidth driving a 10Ω load is second only to the EL2009 and insures stability in fast op amp feedback loops. Elantec has applied for patents on unique circuitry within the EL2008.

Used as an open loop buffer, the EL2008's low output impedance (1Ω) gives a gain of 0.99 when driving a 100Ω load and 0.9 driving a 10Ω load. The EL2008 has output short circuit current limiting which will protect the device under both a DC fault condition and AC operation with reactive loads.

The EL2008 is constructed using Elantec's proprietary Complementary Bipolar process that produces PNP and NPN transistors with essentially identical AC and DC characteristics. In the EL2008, the Complementary Bipolar process also insulates the package's metal heat sink tab from all supply voltages. Therefore the tab may be mounted to an external heat sink or the chassis without an insulator.

The EL2008CT is specified for operation over the 0°C to +75°C temperature range and is provided in a 5-lead TO-220 plastic power package.

Simplified Schematic



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Manufactured under U.S. Patent No. 4,833,424 and 4,827,223 and U.K. Patent No. 2217134.

December 1995 Rev. E

Absolute Maximum Ratings (25°C)

V_S	Supply Voltage (V+ − V−)	±18V or 36V	T_A	Operating Temperature Range	0°C to +75°C
V_{IN}	Input Voltage (Note 1)	±15 or V_S	T_J	Operating Junction Temp	175°C
I_{IN}	Input Current (Note 1)	±50 mA	T_{ST}	Storage Temp Range	−65°C to +150°C
P_D	Power Dissipation (Note 2)	See Curves	T_{LD}	Lead Solder Temp <10 seconds	300°C

Important Note:

All parameters having Min/Max specifications are guaranteed. The Test Level column indicates the specific device testing actually performed during production and Quality inspection. Elantec performs most electrical tests using modern high-speed automatic test equipment, specifically the LTX77 Series system. Unless otherwise noted, all tests are pulsed tests, therefore $T_J = T_C = T_A$.

Test Level	Test Procedure
I	100% production tested and QA sample tested per QA test plan QCX0002.
II	100% production tested at T_A = 25°C and QA sample tested at T_A = 25°C, T_{MAX} and T_{MIN} per QA test plan QCX0002.
III	QA sample tested per QA test plan QCX0002.
IV	Parameter is guaranteed (but not tested) by Design and Characterization Data.
V	Parameter is typical value at T_A = 25°C for information purposes only.

Electrical Characteristics V_S = ±15V, R_S = 50Ω, unless otherwise specified

Parameter	Description	Test Conditions			Limits			Test Level	Units
		V_{IN}	Load	Temp	Min	Typ	Max		
V_{OS}	Output Offset Voltage	0	∞	25°C	−40	10	+40	I	mV
				T_{MIN}, T_{MAX}	−50		+50	IV	mV
I_{IN}	Input Current	0	∞	25°C	−35	−5	+35	I	µA
				T_{MIN}, T_{MAX}	−50		+50	IV	µA
R_{IN}	Input Impedance	±12V	100Ω	25°C	0.5	2		I	MΩ
A_{V1}	Voltage Gain	±10V	∞	25°C	0.985	0.9995		I	V/V
A_{V2}	Voltage Gain	±10V	10Ω	25°C	0.88	0.91		I	V/V
A_{V3}	Voltage Gain, V_S = ±15V	±3V	10Ω	25°C	0.87	0.89		I	V/V
V_{01}	Output Voltage Swing	±14V	100Ω	25°C	±13			I	V
V_{02}	Output Voltage Swing	±12V	10Ω	25°C	±10.5	±11		I	V
R_{01}	Output Impedance	±10V	±10 mA	25°C		1.8	2.5	I	Ω
R_{02}	Output Impedance	±10V	±1A	25°C		0.8	1.0	I	Ω
I_O	Output Current	±12V	(Note 3)	25°C	1.4	1.8		I	A
				T_{MIN}, T_{MAX}	1			IV	A
I_S	Supply Current	0	∞	25°C	12	17	26	I	mA
PSRR	Supply Rejection (Note 4)	0	∞	25°C	60			I	dB
V_S+, V_S−	Supply Sensitivity (Note 5)		∞	25°C			2	I	mV/V

TD is 3.9in

Electrical Characteristics $V_S = \pm 15V$, $R_S = 50\Omega$, unless otherwise specified

Parameter	Description	Test Conditions			Limits			Test Level	Units
		V_{IN}	Load	Temp	Min	Typ	Max		
SR_1	Slew Rate	$\pm 10V$	50Ω	25°C		2500		V	V/μs
	(Note 6)	$\pm 10V$	10Ω	25°C		1500		V	V/μs
SR_2	Slew Rate (Note 7)	$\pm 5V$	10Ω	25°C		800		V	V/μs
t_r, t_f	Rise/Fall Time	100 mV	10Ω	25°C		7		V	ns
BW	−3 dB Bandwidth	100 mV	10Ω	25°C		55		V	MHz
C_{IN}	Input Capacitance			25°C		25		V	pF
THD				25°C			1	I	%

Note 1: If the input exceeds the ratings shown (or the supplies) or if the input voltage exceeds ±7.5V then the input current must be limited to ±50 mA. See the application hints for information.

Note 2: The maximum power dissipation depends on package type, ambient temperature and heat sinking. See the characteristic curves for more details.

Note 3: Force the input to +12V and the output to +10V and measure the output current. Repeat with −12V and −10V on the output.

Note 4: $V_S = \pm 4.5V$ then V_S is changed to ±18V.

Note 5: $V_S+ = +15V$, $V_S- = -4.5V$ then V_S- is changed to −18V and $V_S- = -15V$, $V_S+ = +4.5V$ then V_S+ is changed to +18V.

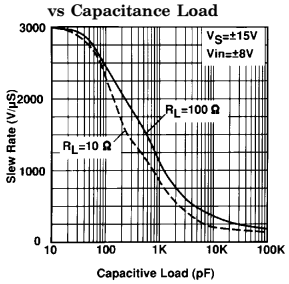
Note 6: Slew Rate is measured between $V_{OUT} = +5V$ and −5V.

Note 7: Slew Rate is measured between $V_{OUT} = +2.5V$ and −2.5V.

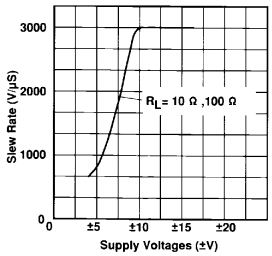
TD is 1.8in

Typical Performance Curves

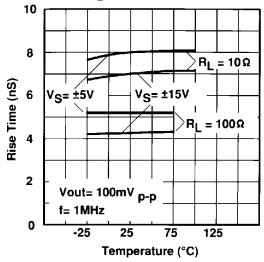
Slew Rate vs Capacitance Load



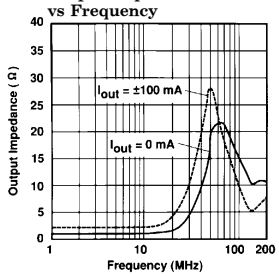
Slew Rate vs Supply Voltage



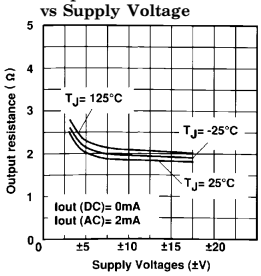
Rise Time vs Temperature



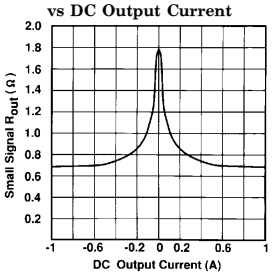
Output Impedance vs Frequency



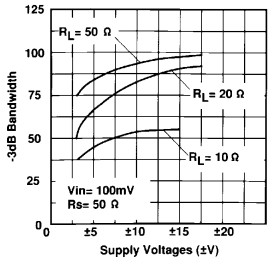
Output Resistance vs Supply Voltage



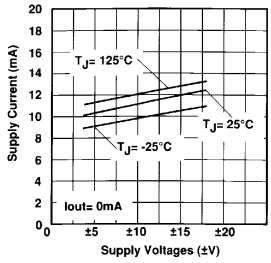
Small Signal Output Resistance vs DC Output Current



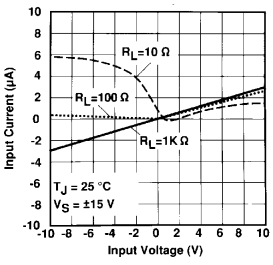
−3 dB Bandwidth vs Supply Voltage



Quiescent Supply Current vs Supply Voltage



Input Current vs Input Voltage



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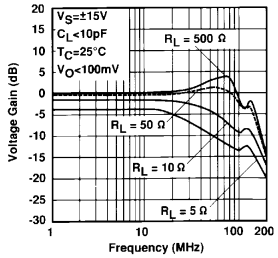
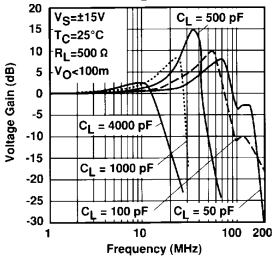
Typical Performance Curves — Contd.

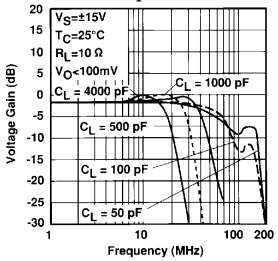
Voltage Gain vs Frequency at Various Resistive Loads



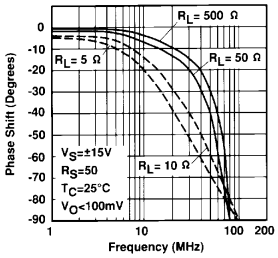
Voltage Gain vs Frequency at Various Capacitive Loads



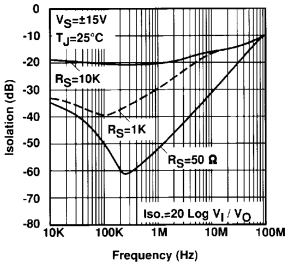
Voltage Gain vs Frequency at Various Capacitive Loads



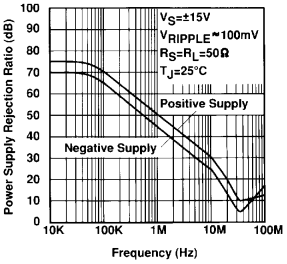
Phase Shift vs Frequency at Various Resistive Loads



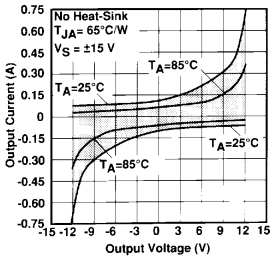
Reverse Isolation vs Frequency



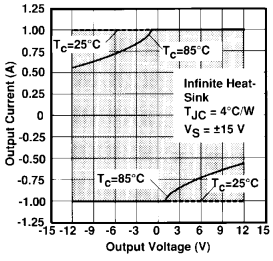
Power Supply Rejection Ratio vs Frequency



Active operating area.



Active operating area.



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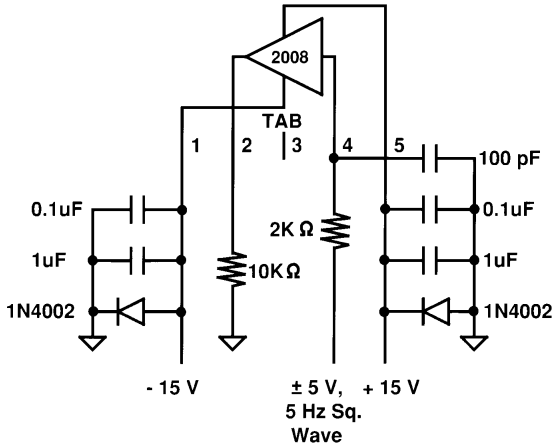
Burn-In Circuit



Applications Information

The EL2008 is a monolithic buffer amplifier built on Elantec's proprietary dielectric isolation process that produces NPN and PNP transistors with essentially identical DC and AC characteristics. The EL2008 takes full advantage of the complementary process with a unique circuit topology.

Elantec has applied for two patents based on the EL2008's topology. The patents relate to the base drive and feedback mechanism in the buffer. This feedback makes 3000 V/μs slew rates with 10Ω load possible with modest supply current.

Power Supplies

The EL2008 may be operated with single or split supplies with total voltage difference between 10V ($\pm$5V) and 36V ($\pm$18V). However, bandwidth, slew rate and output impedance are affected by total supply voltages below 20V ($\pm$10V) as shown by the characteristic curves. It is not necessary to use equal split value supplies. For example $-$5V and $+$12V would be excellent for signals from $-$2V to $+$9V.

Bypass capacitors from each supply pin to ground are highly recommended to reduce supply ringing and the interference it can cause. At a minimum a 10 μF tantalum capacitor in parallel with a 0.1 μF capacitor with short leads should be used for both supplies.

Input Characteristics

The input to the EL2008 looks like a resistance in parallel with about 25 pF in addition to a DC bias current. The DC bias current is due to the mismatch in beta and collector current between the NPN and PNP transistors connected to the input pin. The bias current can be either positive or negative. The change in input current with input voltage (R_{IN}) is affected by the output load, beta and the internal boost. R_{IN} can actually appear negative over portions of the input range in some units. A few typical input current (I_{IN}) curves are shown in the characteristic curves.

Internal clamp diodes from the input to the output are provided. These diodes protect the transistor base emitter junctions and limit the boost current during slew to avoid saturation of internal transistors. The diodes begin conduction at about $\pm$2.5V input to output differential. When that happens the input resistance drops dramatically. The diodes are rated at 50 mA. When conducting they have a series resistance of about 20Ω. If the output of the EL2008 is accidentally shorted it is possible that some devices driving the EL2008's input could be damaged or destroyed driving the EL2008's load through the diodes while the EL2008 is unaffected. In such cases a resistor in series with the input of the EL2008 can limit the current.

Applications Information — Contd.

Source Impedance

The EL2008 has good input to output isolation. Open loop, capacitive and resistive sources up to 100 kΩ present no oscillation problem driving resistive loads as long as care is used in board layout to minimize output to input coupling and the supplies are properly bypassed. When driving capacitive loads in the 100 pF to 1000 pF region source resistances above 25Ω can cause peaking and oscillation. Such problems can be eliminated by placing a capacitor from the EL2008's input to ground. The value should be about ¼ the load capacitance. In a feedback loop there is a speed penalty and a possibility of oscillation when the EL2008 is driven with a source impedance of 200Ω or more. Significant phase shift can occur due to the EL2008's 25 pF input capacitance. Inductive sources can cause oscillations. A series resistor of a few hundred ohms to 1 kΩ will usually solve the problem.

Current Limit

The EL2008 has internal current limiting to protect the output transistors. The current limit is about 1.5A at room temperature and decreases with junction temperature. At 150°C junction temperature it is above 1A.

Heat Sinking

A suitable heat sink will be required for most applications. The thermal resistance junction to case for the TO-220 package is 4°C per watt. No voltage appears at the heat sink tab so no precautions need to be taken to avoid shorting the tab to a supply voltage or ground. As there is a small parasitic capacitance between the tab and the buffer circuitry, it is recommended that the tab be connected to AC ground (either supply voltage or DC ground). The center lead is internally connected to the tab so the connection can be made at the tab or the center lead.

Parallel Operation

If more than 1A is required or if heat management is a problem, several EL2008s may be paralleled together. The result is as through each device was driving only part of the load. For example, if two units are paralleled then a 5Ω load looks like 10Ω to each EL2008. Of course, parallel operation reduces both the input and output impedance and increases bias current. But there is no increase in offset voltage. Three units in parallel can drive a 3Ω load ±10V at 2500 V/μs. The output impedance will be about 0.33Ω.

Resistive Loads

The DC gain of the EL2008 is the product of the unloaded gain (0.999) and the voltage divider formed by the device output resistance and the load resistance.

$$A_V = 0.999^* (R_L/R_L + R_{OUT})$$

The high frequency response varies with the load resistance as shown by the characteristic curves. Both gain and phase are shown. If the 80 MHz peaking is undesireable when driving load resistors greater than 50Ω, an RC snubber circuit can be used from output to ground. The capacitive load section discusses snubber usage in more detail.

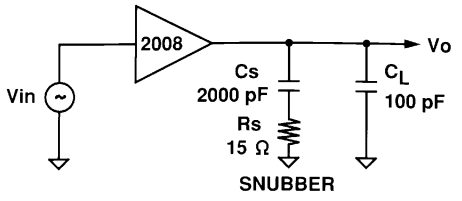
Capacitive Loads

The EL2008 is not stable driving purely capacitive loads between 100 pF and 500 pF. Purely capacitive loads from 500 pF to 1000 pF will also have excessive peaking as shown in the characteristic curves. The squarewave response will have large overshoots and ring for hundreds of nanoseconds.

When driving capacitive loads, stability can be achieved and peaking and ringing can be mini-

Applications Information — Contd.

mized either by adding a 50Ω (or less) load in parallel with the capacitive load or by an RC snubber circuit from output to ground. The snubber values can be found empirically by observing a squarewave or the frequency response. First just put a resistor alone from the output to ground until the desired response is achieved. The gain will be reduced due to the output resistance of the EL2008 and power consumption will be high. Then put a capacitor in series with the resistor to restore gain at low frequencies and eliminate the DC current. Start with a small capacitor and increase until the response is optimum. The figure below shows an example of an EL2008 driving a 100 pF load.



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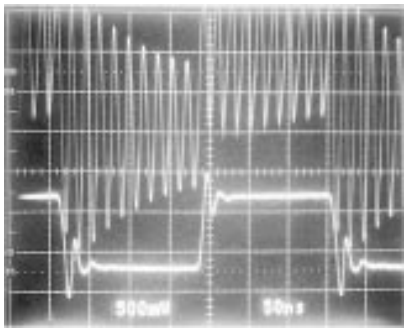

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Driving a pure capacitive load. Top trace is without a snubber. Bottom trace is with a snubber circuit.

Inductive Loads

The EL2008 with its 1A output current can drive small motors and other inductive loads. The EL2008's current limiting into inductive loads does NOT in and of itself cause spikes and kickbacks. However, if the EL2008 is in current limit and the input voltage is changing very quickly (i.e., a squarewave) the inductive load can kick the output beyond the supply voltages. Motors are also able to generate kickback voltages when the EL2008 is in current limit.

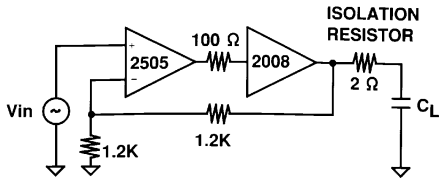
To prevent damage to the EL2008 when the output kicks beyond the supplies it is recommended that catch diodes be placed from each supply to the output.

Op Amp Booster

The EL2008 can boost the output drive of almost any monolithic op amp. If the phase shift in the EL2008 is low at the op amp's unity gain frequency, no additional frequency compensation is required. An op amp followed with the EL2008 can drive loads as low as 10Ω to ±10V.

Driving capacitive loads with any closed loop system creates special problems. The open loop output impedance works into the load capacitance to generate phase lag which can make the loop unstable. The EL2008 output impedance is less than 10Ω from DC to 30 MHz. But a capacitive load of 1000 pF will generate about 45 degrees of phase shift at 30 MHz. More capacitance will cause the problem at lower frequency.

With enough capacitance even slow op amps will become unstable. The simplest way to drive capacitive loads is to isolate them from the feedback with a series resistor. 1Ω to 5Ω is usually enough but the final value will depend on the op amp used and the range of load capacitance.



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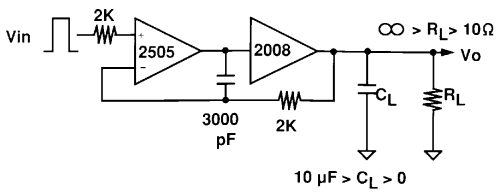
C_L		t_r		O.S.
13	pF	45	ns	20%
470	pF	50	ns	20%
1000	pF	55	ns	30%
3300	pF	60	ns	30%
0.1	µF	350	ns	0%
1	µF	4	µs	0%
5	µF	20	µs	0%

Applications Information — Contd.

Unfortunately the isolation resistor is not inside the op amp feedback loop and cannot be neglected when computing the DC voltage gain into a resistive load. If load dependent DC gain is not tolerable then additional high frequency feedback from the op amp output (the EL2008 input) and an isolation resistor from the buffer output can be used to stabilize the loop. This configuration requires the op amp to be unity gain stable. This feedback method will allow the EL2008 to boost the output of the EHA2505 amplifier below and serve as a variable, bipolar 1A voltage supply with short circuit protection.



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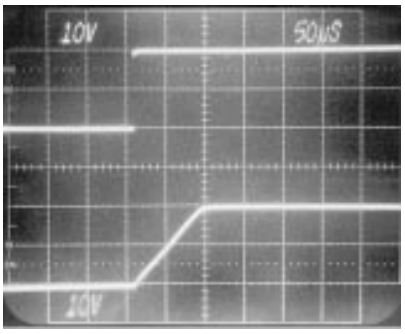
Slew Rate = $1A/C_L$

Video Distribution Amplifier

The EL2008 can drive 15 double matched 75Ω cables. If the EL2008 is used within an op amp feedback loop the output levels are independent of loading. The circuit below accepts 1 of 2 inputs and drives 15 cables. Pin 8 of the EL2020 (Disable) is used to multiplex between the inputs and can be easily expanded to accept more inputs. The circuit as shown when fully loaded has differential phase $<0.1°$ and differential gain $<0.1\%$. The 100Ω resistor at the EL2008 input (R1) is necessary to stabilize the loop. The 100Ω resistor at the EL2008 output (R2) to the −12V supply, insures that the EL2008 sources current even when the output voltage is at 0V. This is necessary to achieve the excellent differential gain and phase values. More information about driving cables can be found in the EL2003 data sheet. See the EL2020 data sheet to learn more about using it as a multiplexer.



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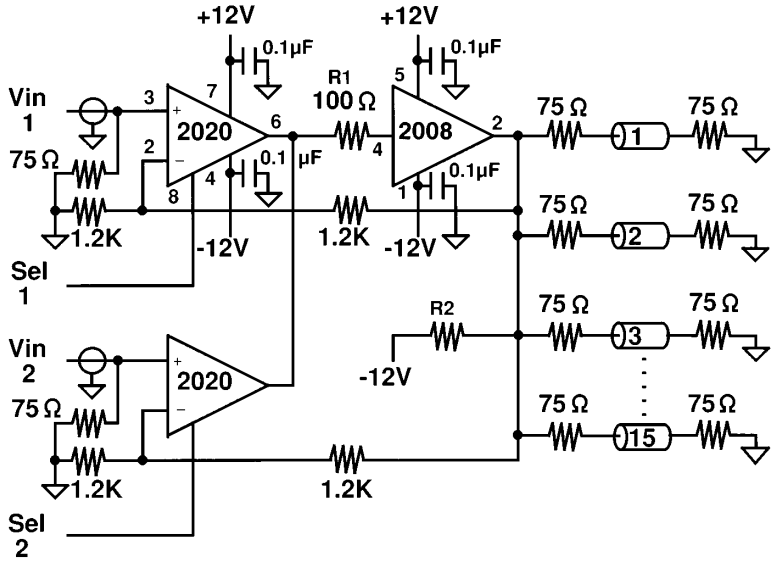
Input (top trace) and output (bottom trace) of EHA2505 op amp boosted by EL2008.

Video Mux and Distribution Amplifier



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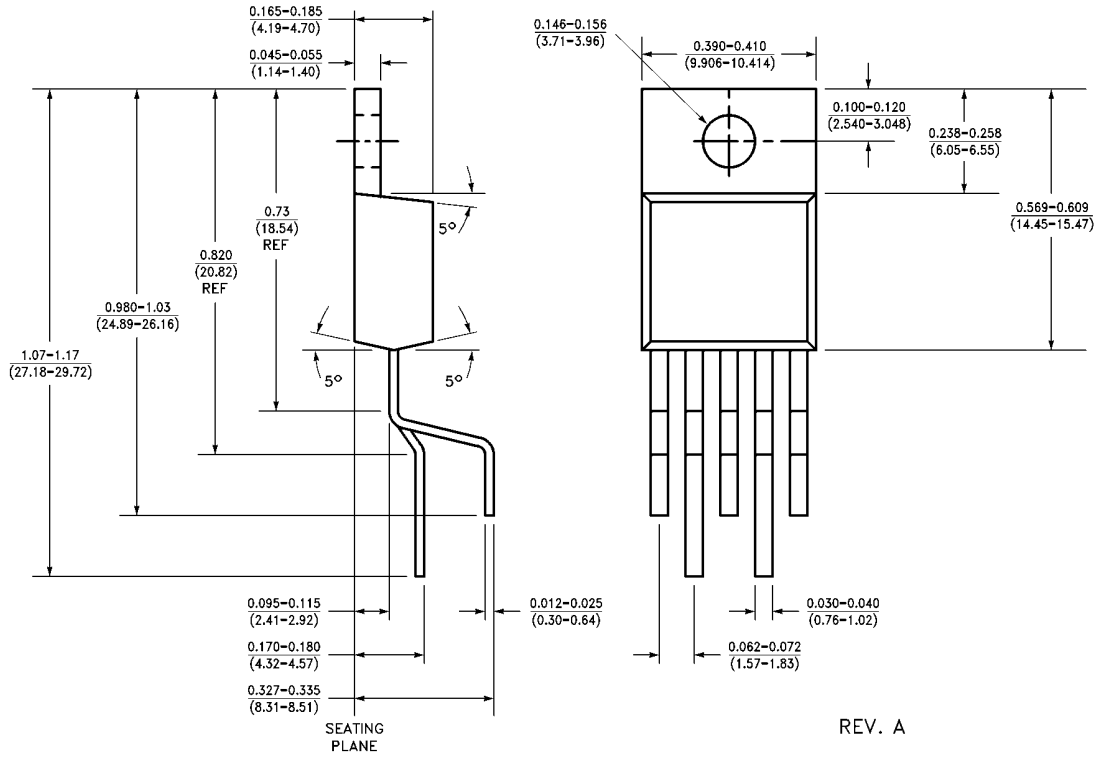
EL2008 Macromodel

```
* Connections:      +input
*                   |     +Vsupply
*                   |     |     -Vsupply
*                   |     |     |     output
*                   |     |     |     |
.subckt M2008       4     5     1     2
*
* Input Stage
*
e1 10 0 4 0 1.0
r1 10 0 1K
rh 10 11 1K
ch 11 0 2.65pF
rc 11 12 10K
cc 12 0 0.159pF
e2 13 0 12 0 1.0
*
* Output Stage
*
q1 1 13 14 qp
q2 5 13 15 qn
q3 5 14 16 qn 15
q4 1 15 19 qp 15
r2 16 2 0.4
r3 19 2 0.4
c1 14 0 0.6pF
c2 15 0 0.6pF
i1 5 14 1.2mA
i2 15 1 1.2mA
*
* Bias Current
*
iin+ 4 0 5μA
*
* Models
*
.model qn npn (is=5e-15 bf=1500)
.model qp pnp (is=5e-15 bf=1500)
.ends
```

TD is 5.2in

EL2008C
55 MHz 1 Amp Buffer Amplifier

Package Outline



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